

## 1N5807, 1N5809, 1N5811

# **Axial Leaded Hermetically Sealed Superfast Rectifier Diodes**

#### **HIGH-RELIABILITY PRODUCTS**

#### **Features**

- Very low reverse recovery time
- Hermetically sealed in lead borosilicate glass sleeve
- Low switching losses
- Soft, non-snap off, recovery characteristics
- Very low forward voltage drop

#### **Quick reference data**

 $V_{R} = 50 - 150V$ 

 $I_{E} = 6.0A$ 

 $t_{rr} = 30 \text{ ns}$ 

 $I_{R} = 5.0 \mu A$ 

#### **Absolute Maximum Rating**

Electrical specifications @  $T_A = 25$ °C unless otherwise specified.

Parameter	Symbol	1N5807	1N5809	1N5811	Units
Working reverse voltage	$V_{_{\mathrm{RWM}}}$	50	100	150	V
Repetitive reverse voltage	$V_{RRM}$	50	100	150	V
Average forward current (@ 75°C, lead length = 0.375")	I <sub>F (AV)</sub>	6.0			А
Repetitive surge current (@ 55°C in free air, lead length = 0.375")	I <sub>FRM</sub>	25			Α
Non-repetitive surge current $(t_p = 8.3 \text{ms}, @V_R \& T_{jmax})$	I <sub>FSM</sub>	125			Α
Storage temperature range	T <sub>stg</sub>	-65 to +175			٥С
Operating temperature range	T <sub>OP</sub>	-65 to +175			°C

# Electrical Characteristics (T=25°C unless otherwise specified)

Parameter	Symbol	1N5807	1N5809	1N5811	Units
Average forward current max. (pcb mounted; T <sub>A</sub> = 55°C)					
for sine wave	I <sub>F(AV)</sub>			Α	
for square wave $(d = 0.5)$	I <sub>F(AV)</sub>	1.8			Α
Average forward current max. $(T_L = 55^{\circ}C; L = 3/8")$					
for sine wave	I <sub>F(AV)</sub>		5.7		Α
for square wave $(d = 0.5)$	I <sub>F(AV)</sub>		6.0		Α
$I^2$ t for fusing (t = 8.3ms) max.	l²t		32		A <sup>2</sup> s
Forward voltage drop max. @ $I_F = 4.0A$ , $T_J = 25$ °C	V <sub>F</sub>		0.875		V
Reverse current max.					
@ V <sub>RWM</sub> , T <sub>i</sub> = 25°C	I <sub>R</sub>		5.0		μA
@ V <sub>RWM</sub> , T <sub>j</sub> = 100°C	I <sub>R</sub>	150			μA
Reverse recovery time max.					
1.0A I <sub>F</sub> to 1.0 I <sub>R</sub> .	t <sub>rr</sub>		30		ns
Recovers to 0.1A $I_{RR}$ .					
Junction capacitance typ. $@V_R = 5V, f = 1MHz$	C <sub>j</sub>		pF		

## **Thermal Characteristics** •

Parameter	Symbol	1N5807	1N5809	1N5811	Units
Thermal resistance - junction to lead Lead length = 0.375"	$R_{\theta JL}$	22		°C/W	
Thermal resistance - junction to ambient On 0.06" thick pcb. 1oz. copper	R <sub>ej A</sub>	90		°C/W	

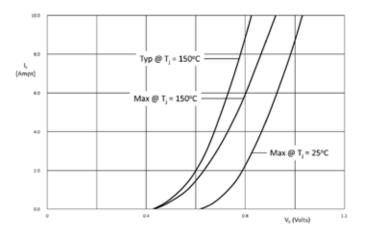


Figure 1. Forward voltage drop as a function of forward current.

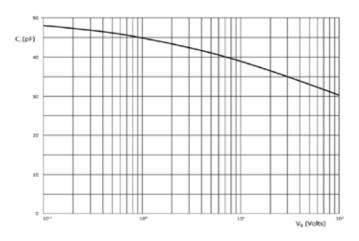
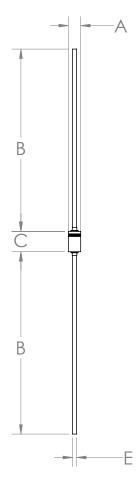


Figure 2. Typical junction capacitance as a function of reverse voltage.

#### **Outline Drawing**



Dimensions					
Inches		ches	Millir	neters	
DIM -	MIN	MAX	MIN	MAX	
Α	0.115	0.142	2.92	3.61	
В	0.900	1.30	22.86	33.02	
С	0.130	0.300	3.30	7.62	
Е	0.036	0.042	0.91	1.07	

These products are qualified to MIL-PRF-19500/477 and are preferred parts as listed in Qualified Products Database (QPD). They can be supplied fully released as JANTX, JANTXV and JANS.